TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT process)

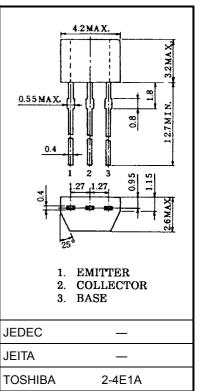
2SA1049

Audio Frequency Amplifier Applications

- Small package.
- High breakdown voltage: VCEO = -120 V
- High hFE: hFE = 200~700
- Excellent hFE linearity: hFE (IC = -0.1 mA)/hFE (IC = -2 mA) = 0.95 (typ.)
- Low noise: NF = 1dB (typ.), 10dB (max)
- Complementary to 2SC2459.

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	-120	V
Collector-emitter voltage	V _{CEO}	-120	V
Emitter-base voltage	V _{EBO}	-5	V
Collector current	Ι _C	-100	mA
Base current	Ι _Β	-20	mA
Collector power dissipation	P _C	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.13 g (typ.)

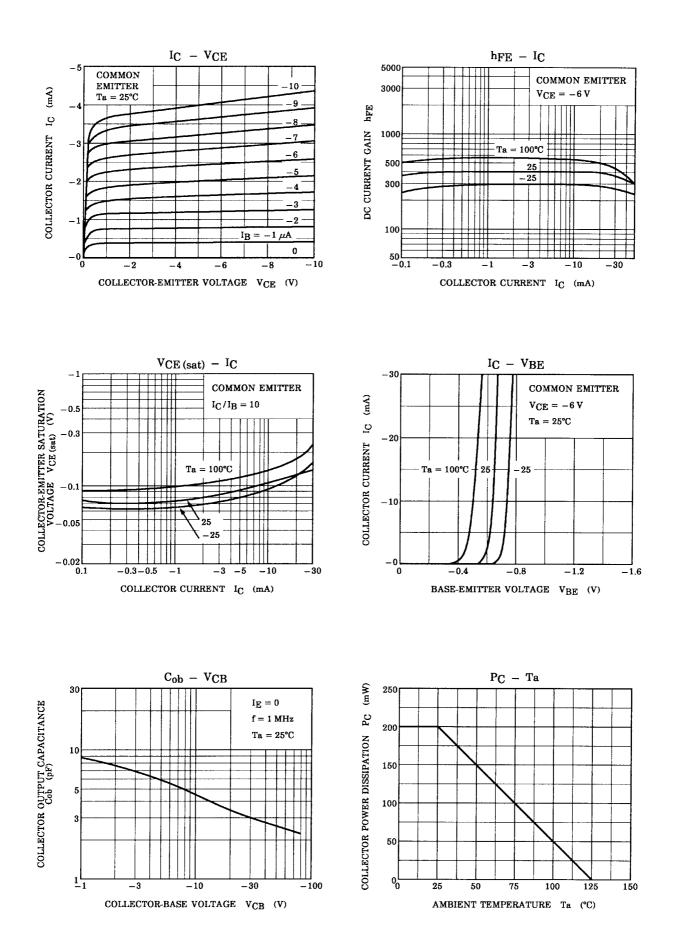
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = -120 \text{ V}, \text{ I}_{E} = 0$			-0.1	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = -5 V, I_C = 0$	_	_	-0.1	μ A
DC current gain	h _{FE} (Note)	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -2 \text{ mA}$	200	_	700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = -10 \text{ mA}, I_{B} = -1 \text{ mA}$	_	—	-0.3	V
Transition frequency	f _T	$V_{CE} = -6 \text{ V}, \text{ I}_{C} = -1 \text{ mA}$	_	100	_	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10 V$, $I_E = 0$, $f = 1 MHz$	_	4		pF
Noise figure	NF	V_{CE} = -6 V, I _C = -0.1 mA f = 1 kHz, R _G = 10 k Ω	_	1.0	10	dB

Note: hFE classification GR: 200~400, BL: 350~700

Unit: mm

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